

Eric Lambers

List of Publications by Year in descending order

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6
papers

233
citations

1478505

6
h-index

1872680

6
g-index

6
all docs

6
docs citations

6
times ranked

397
citing authors

#	ARTICLE	IF	CITATIONS
1	TaN interface properties and electric field cycling effects on ferroelectric Si-doped HfO ₂ thin films. Journal of Applied Physics, 2015, 117, .	2.5	165
2	Valence- and Conduction-Band Offsets for Atomic-Layer-Deposited Al ₂ O ₃ on (010) (Al _{0.14} Ga _{0.86}) ₂ O ₃ . Journal of Electronic Materials, 2019, 48, 1568-1573.	2.2	19
3	Band alignment of atomic layer deposited SiO ₂ on (010) (Al _{0.14} Ga _{0.86}) ₂ O ₃ . Journal of Vacuum Science and Technology B: Nanotechnology and Microelectronics, 2018, 36, .	1.2	18
4	Valence band offsets for ALD SiO ₂ and Al ₂ O ₃ on (In _x Ga _{1-x}) ₂ O ₃ for x = 0.25–0.74. APL Materials, 2019, 7, .	5.1	14
5	Band Offsets for Atomic Layer Deposited HfSiO ₄ on (Al _{0.14} Ga _{0.86}) ₂ O ₃ . ECS Journal of Solid State Science and Technology, 2018, 7, P519-P523.	1.8	9
6	Valence and conduction band offsets for sputtered AZO and ITO on (010) (Al _{0.14} Ga _{0.86}) ₂ O ₃ . Semiconductor Science and Technology, 2019, 34, 025006.	2.0	8